

Optoelectronic Devices

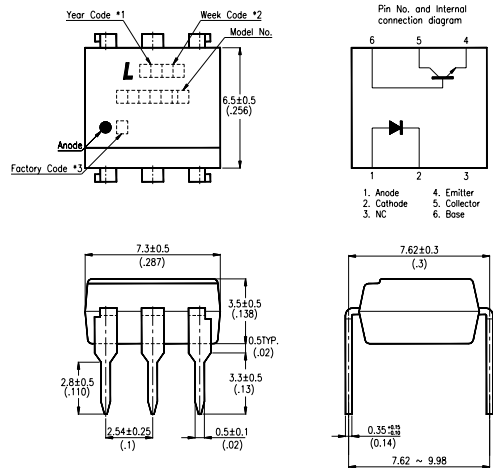
Order code	Manufacturer code	Description
58-0880	CNY17-1	CNY17-1 TRANSISTOR OPTOISOLATOR
58-0884	CNY17-2	CNY17-2 TRANSISTOR OPTOISOLATOR
58-0886	CNY17-3	CNY17-3 TRANSISTOR OPTOISOLATOR

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The enclosed information is believed to be correct, Information may change 'without notice' due to product improvement. Users should ensure that the product is suitable for their use. E. & O. E.	Revision A 04/07/2003

Features

- High collector-emitter voltage ($V_{CE0} : 70V$)
- High input-output isolation voltage :
($V_{ISO} : 5,000V_{rms}$)
- Directly connectable to TTL
- UL approved (No. E113898)
- VDE approved (No. 094722)
- FIMKO approved (No. 209049)
- SEMKO approved (No. 9943380/01-20)
- NEMKO approved (No. P99102464)
- DEMKO approved (No. 99-04182)
- CSA approve in progress
- Options Available :
 - Leads with 0.4" (10.16mm) Spacing (M Type)
 - Lead Bends for Surface Mounting (S Type)
 - Tape and Reel of Type I for SMD (Add "-TA" Suffix)
 - Tape and Reel of Type II for SMD (Add "-TA1" Suffix)
 - VDE 0884 Approvals (Add "-V" Suffix)

Package Dimensions



Applications

1. Telephone sets, telephone exchangers
2. System appliances, measuring instruments
3. Signal transmission between circuits of different potentials and impedances

NOTES :

1. Year date code.
2. 2-digit work week.
3. Factory code shall be marked (Z : Taiwan, Y : Thailand).
4. Model No.: CNY17-1 ; CNY17-2 ; CNY17-3 ; CNY17-4
5. All dimensions are in millimeters (inches).
6. Tolerance is $\pm 0.25mm$ (.010") unless otherwise noted.
7. Specifications are subject to change without notice.

Ordering Information

Part Number	Package	Safety Standard Approval	Application part number
CNY17-1 CNY17-1M CNY17-1S CNY17-1S-TA CNY17-1S-TA1	6-pin DIP 6-pin (leads with 0.4" spacing) 6-pin (lead bends for surface mount) 6-pin (tape and reel packaging of type I) 6-pin (tape and reel packaging of type II)	<ul style="list-style-type: none"> • UL approved • FIMKO approved • SEMKO approved • NEMKO approved • DEMKO approved • CSA approve in progress 	CNY17-1
CNY17-2 CNY17-2M CNY17-2S CNY17-2S-TA CNY17-2S-TA1	6-pin DIP 6-pin (leads with 0.4" spacing) 6-pin (lead bends for surface mount) 6-pin (tape and reel packaging of type I) 6-pin (tape and reel packaging of type II)		CNY17-2
CNY17-3 CNY17-3M CNY17-3S CNY17-3S-TA CNY17-3S-TA1	6-pin DIP 6-pin (leads with 0.4" spacing) 6-pin (lead bends for surface mount) 6-pin (tape and reel packaging of type I) 6-pin (tape and reel packaging of type II)		CNY17-3
CNY17-4 CNY17-4M CNY17-4S CNY17-4S-TA CNY17-4S-TA1	6-pin DIP 6-pin (leads with 0.4" spacing) 6-pin (lead bends for surface mount) 6-pin (tape and reel packaging of type I) 6-pin (tape and reel packaging of type II)		CNY17-4
CNY17-1-V CNY17-1M-V CNY17-1S-V CNY17-1STA-V CNY17-1STA1-V	6-pin DIP 6-pin (leads with 0.4" spacing) 6-pin (lead bends for surface mount) 6-pin (tape and reel packaging of type I) 6-pin (tape and reel packaging of type II)	<ul style="list-style-type: none"> • VDE approved 	CNY17-1
CNY17-2-V CNY17-2M-V CNY17-2S-V CNY17-2STA-V CNY17-2STA1-V	6-pin DIP 6-pin (leads with 0.4" spacing) 6-pin (lead bends for surface mount) 6-pin (tape and reel packaging of type I) 6-pin (tape and reel packaging of type II)		CNY17-2
CNY17-3-V CNY17-3M-V CNY17-3S-V CNY17-3STA-V CNY17-3STA1-V	6-pin DIP 6-pin (leads with 0.4" spacing) 6-pin (lead bends for surface mount) 6-pin (tape and reel packaging of type I) 6-pin (tape and reel packaging of type II)		CNY17-3
CNY17-4-V CNY17-4M-V CNY17-4S-V CNY17-4STA-V CNY17-4STA1-V	6-pin DIP 6-pin (leads with 0.4" spacing) 6-pin (lead bends for surface mount) 6-pin (tape and reel packaging of type I) 6-pin (tape and reel packaging of type II)		CNY17-4

Ratings and Characteristics

Absolute Maximum Ratings

(Ta=25°C)

Parameter		Symbol	Rating	Unit
Input	Forward Current	I _F	60	mA
	Reverse Voltage	V _R	6	V
	Power Dissipation	P	100	mW
Output	Collector-Emitter Voltage	V _{CEO}	70	V
	Emitter-Collector Voltage	V _{ECO}	7	V
	Collector-Base Voltage	V _{CBO}	70	V
	Collector Current	I _C	150	mA
	Collector Power Dissipation	P _C	150	mW
Total Power Dissipation		P _{tot}	250	mW
*1.Isolation Voltage		V _{iso}	5,000	V _{rms}
Operating Temperature		T _{opr}	-55~+100	°C
Storage Temperature		T _{stg}	-55~+150	°C
*2.Soldering Temperature		T _{sol}	260	°C

*1. AC for 1 minute, R.H. = 40 ~ 60%

Isolation voltage shall be measured using the following method.

(1) Short between anode and cathode on the primary side and between collector, emitter and base on the secondary side.

(2) The isolation voltage tester with zero-cross circuit shall be used.

(3) The waveform of applied voltage shall be a sine wave.

*2. For 10 seconds

Absolute Maximum Ratings

(Ta=25°C)

Parameter		Symbol	Min.	Typ.	Max.	Unit.	Conditions	
Input	Forward Voltage	V _F	—	1.45	1.65	V	I _F =60mA	
	Reverse Current	I _R	—	—	10	μA	V _R =6V	
	Terminal Capacitance	C _t	—	—	100	pF	V=0, f=1MHz	
Output	Collector Dark Current	I _{CEO}	—	—	50	nA	V _{CE} =10V, I _F =0	
	Collector-Emitter Breakdown Voltage	BV _{CEO}	70	—	—	V	I _C =0.1mA I _F =0	
	Emitter-Collector Breakdown Voltage	BV _{ECO}	7	—	—	V	I _E =10 μA I _F =0	
	Collector-Base Breakdown Voltage	BV _{CBO}	70	—	—	V	I _C =0.1mA I _F =0	
Transfer Characteristics	Current *1 Transfer Ratio	CNY17-1	CTR	40	—	80	%	I _F =10mA V _{CE} =5V
		CNY17-2		63	—	125		
		CNY17-3		100	—	200		
		CNY17-4		160	—	320		
	Collector-Emitter Saturation Voltage	V _{CE(sat)}	—	—	0.3	V	I _F =10mA I _C =2.5mA	
	Isolation Resistance	R _{iso}	100	—	—	G Ω	DC500V 40~60%R.H.	
	Floating Capacitance	C _f	—	—	2	pF	V=0, f=1MHz	
Response Time (Rise)	t _r	—	5	10	μS	V _{CC} =10V, I _C =2mA R _L =100 Ω		
Response Time (Fall)	t _f	—	5	10	μS			

$$*1 \text{ CTR} = \frac{I_C}{I_F} \times 100\%$$

Typical Electrical/Optical Characteristic Curves (25°C Ambient Temperature Unless Otherwise Noted)

Fig.1 Forward Current vs. Ambient Temperature

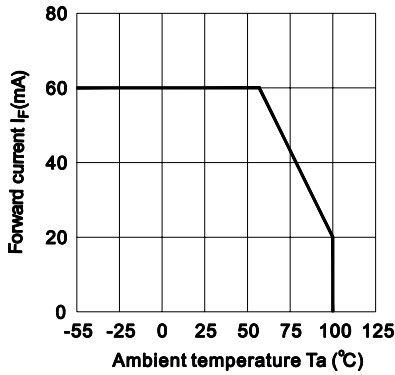


Fig.2 Collector Power Dissipation vs. Ambient Temperature

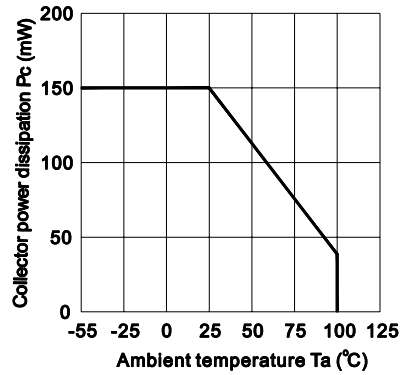


Fig.3 Collector-emitter Saturation Voltage vs. Forward Current

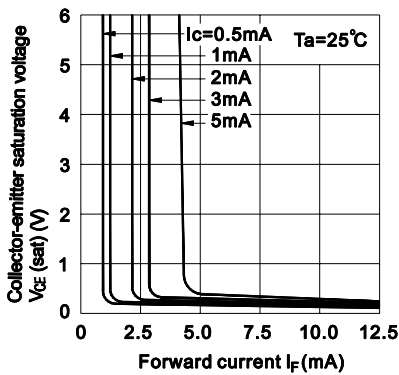


Fig.4 Forward Current vs. Forward Voltage

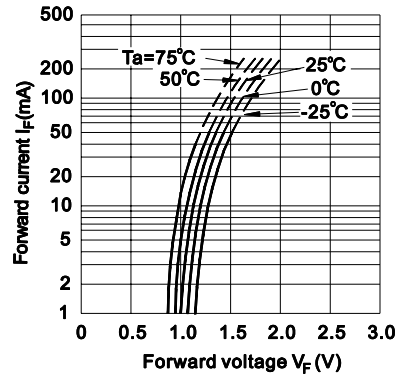


Fig.5 Current Transfer Ratio vs. Forward Current

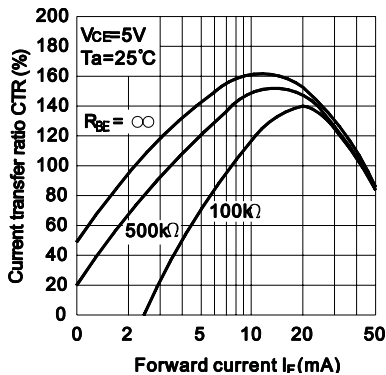


Fig.6 Collector Current vs. Collector-emitter Voltage

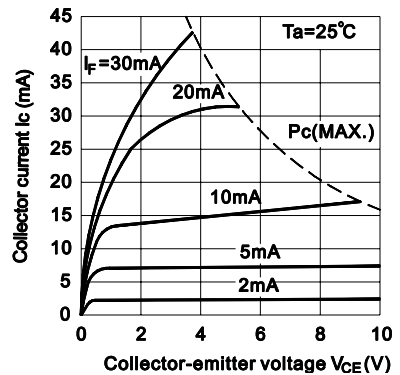


Fig.7 Relative Current Transfer Ratio vs. Ambient Temperature

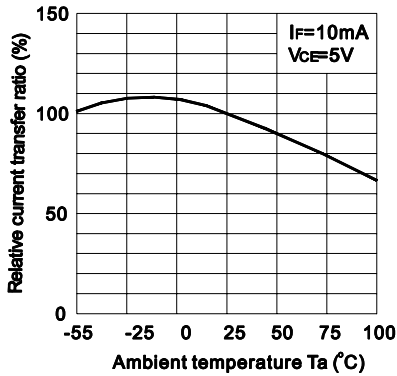


Fig.8 Collector-emitter Saturation Voltage vs. Ambient Temperature

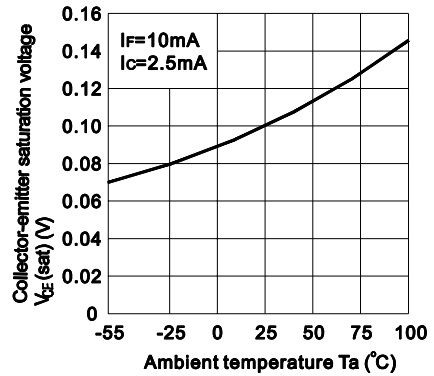


Fig.9 Collector Dark Current vs. Ambient Temperature

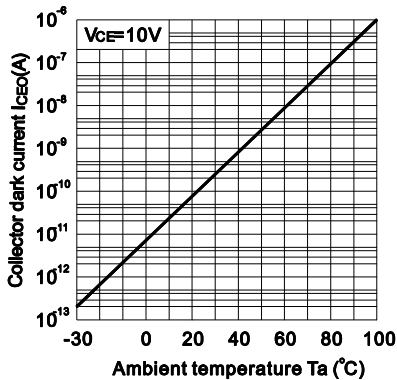


Fig.10 Response Time vs. Load Resistance

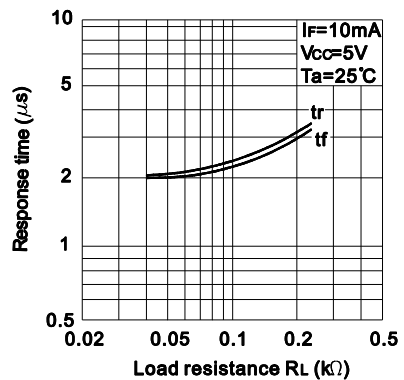
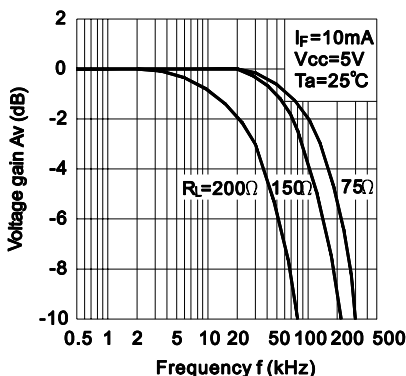
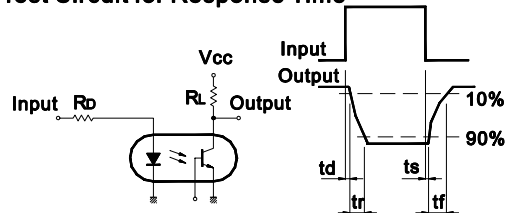


Fig.11 Frequency Response



Test Circuit for Response Time



Test Circuit for Frequency Response

